



### **60V N-Channel Enhancement Mode MOSFET**

Voltage 60 V Current

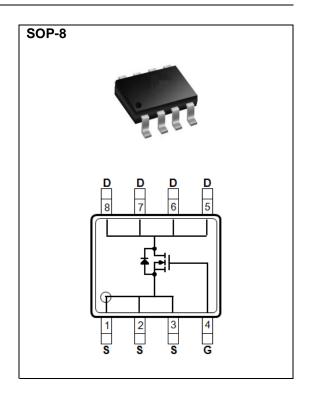
10 A

#### **Features**

- RDS(ON), VGS@10V, ID@10A<12m $\Omega$
- RDS(ON), VGS@4.5V, ID@5.0A<15mΩ</li>
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

### **Mechanical Data**

- Case: SOP-8 package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0029 ounces, 0.083 grams
- Marking: L9434A



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	60	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current	T <sub>A</sub> =25°C	I <sub>D</sub>	10	А	
	T <sub>A</sub> =70°C		8		
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	40	Α	
Power Dissipation	T <sub>A</sub> =25°C	P <sub>D</sub>	2.5	107	
	T <sub>A</sub> =70°C		1.6	W	
Single Pulse Avalanche Energy (Note 5)		E <sub>AS</sub>	5.0	mJ	
Operating Junction and Storage Temperature Range		$T_{J}, T_{STG}$	-55~150	°C	
Typical Thermal resistance					
- Junction to Ambient, t≦10s (Note 6)		$R_{\theta JA}$	50	°C/W	





### **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	$V_{GS}$ =0V, $I_D$ =250uA	60	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	1.0	1.7	2.5	V		
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V,I <sub>D</sub> =10A	-	10.5	12	mΩ		
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V,I <sub>D</sub> =5A	-	12	15	mΩ		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =60V, $V_{GS}$ =0V	-	-	1.0	uA		
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA		
Dynamic (Note 7)								
Total Gate Charge	$Q_g$	V <sub>DS</sub> =30V, I <sub>D</sub> =10A, V <sub>GS</sub> =10V <sup>(Note 1,2)</sup>	-	39	-	nC		
Gate-Source Charge	$Q_gs$		-	6.1	-			
Gate-Drain Charge	$Q_gd$		-	6.7	-			
Input Capacitance	Ciss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1.0MHZ	-	2256	-	pF		
Output Capacitance	Coss		-	145	-			
Reverse Transfer Capacitance	Crss		-	93	-			
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DD}$ =15V, $I_{D}$ =10A, $V_{GS}$ =10V, $R_{G}$ =6 $\Omega$ (Note 1,2)	-	7.5	-			
Turn-On Rise Time	tr		-	36	-			
Turn-Off Delay Time	td <sub>(off)</sub>		-	49	-			
Turn-Off Fall Time	tf		-	12	-			
Drain-Source Diode	Drain-Source Diode							
Maximum Continuous Drain-Source			-	-	10	А		
Diode Forward Current	I <sub>S</sub>							
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1.0A, V <sub>GS</sub> =0V	-	0.67	1.0	V		

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 5. The test condition is L=0.1mH,  $I_{AS}$ =10A,  $V_{DD}$ =50V,  $V_{GS}$ =10V
- 6. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 7. Guaranteed by design, not subject to production testing.





### **TYPICAL CHARACTERISTIC CURVES**

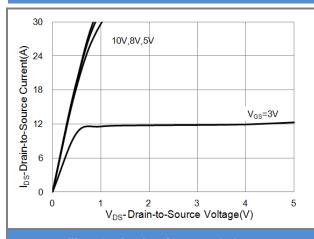
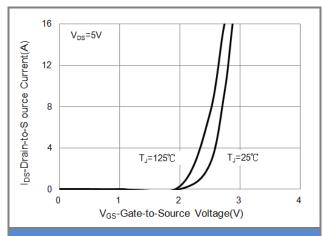


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

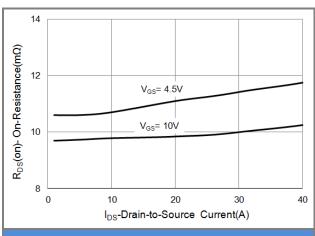


Fig.3 On-Resistance vs. Drain Current

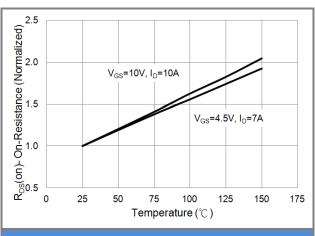


Fig.4 On-Resistance vs. Junction temperature

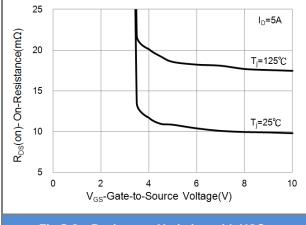


Fig.5 On-Resistance Variation with VGS.

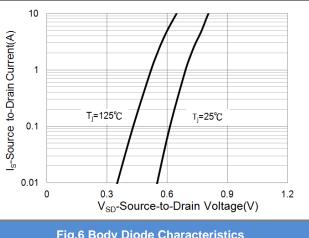
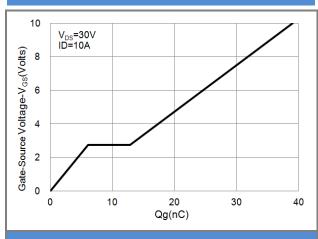


Fig.6 Body Diode Characteristics





### **TYPICAL CHARACTERISTIC CURVES**



**Fig.7 Gate-Charge Characteristics** 

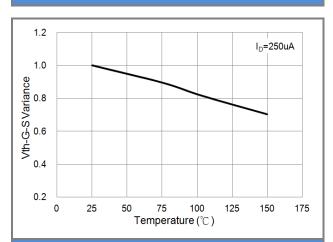
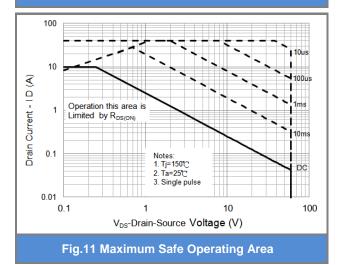


Fig.9 Threshold Voltage Variation with Temperature.



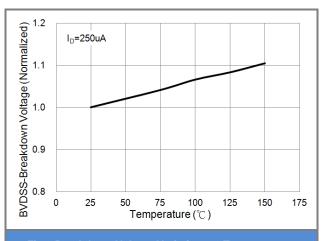


Fig.8 Breakdown Voltage Variation vs. Temperature

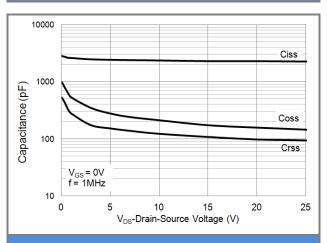


Fig.10 Capacitance vs. Drain-Source Voltage.





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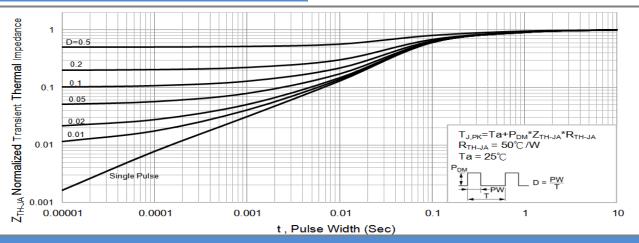


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

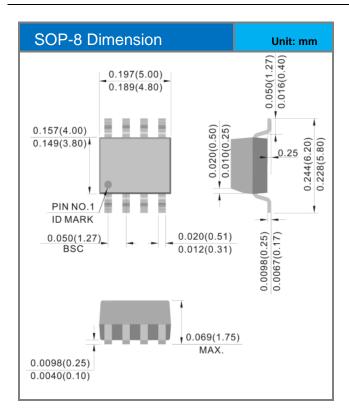


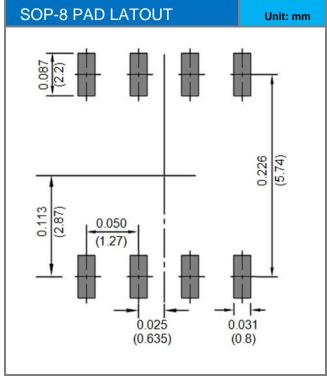


#### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version	
PJL9434A_R2_00001	SOP-8	2.5K pcs / 13" reel	L9434A	Halogen free	

### Packaging Information & Mounting Pad Layout









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